August 2010



FGPF4536 360V, PDP IGBT

Features

- High current capability
- Low saturation voltage: V_{CE (sat)} =1.59 V @ I_C = 50 A
- High input impedance
- Fast switching
- RoHS compliant

Application

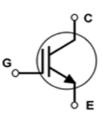
• PDP System



General Description

Using Novel Trench IGBT Technology, Fairchild's new series of trench IGBTs offer the optimum performance for PDP applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Units	
V _{CES}	Collector to Emitter Voltage		360	V	
V _{GES}	Gate to Emitter Voltage		± 30	V	
I _{C pulse(1)*}	Pulsed Collector Current	@ T _C = 25°C	220	А	
P _D	Maximum Power Dissipation	@ T _C = 25°C	28.4	W	
	Maximum Power Dissipation	@ T _C = 100°C	11.4	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T _{stg}	Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	4.4	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	62.5	°C/W

Notes:

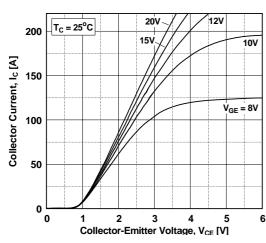
(1) Half Sine Wave, D < 0.01, pluse width < 5 μ sec

* Ic_pluse limited by max Tj

		Device F	Package	ackage Packaging Type		Qty per Tube		Max Qty per Box	
		FGPF4536TU	O-220F Tube		50ea		-		
Electric	al Char	acteristics of the	IGBT T _C = 25	5°C unless otherwise noted					
Symbol		Parameter	Test Conditions		Min.	Тур.	Max.	Units	
Off Charac	teristics								
BV _{CES}	Collector to	Emitter Breakdown Voltage	V _{GE} = 0V, I _C	= 250µA	360	-	-	V	
ΔBV_{CES} ΔT_J	Temperatu Voltage	re Coefficient of Breakdown		$V_{GE} = 0V, I_C = 250\mu A$		0.4	-	V/ºC	
ICES	Collector C	Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0V		-	-	100	μA	
I _{GES}	G-E Leaka	ge Current	$V_{GE} = V_{GES}$	$V_{CE} = 0V$	-	-	±400	nA	
On Charac	oristics		1		1				
V _{GE(th)}		G-E Threshold Voltage $I_{C} = 250 \mu A, V_{CE} = V_{GE}$		V _{CE} = V _{GE}	2.4	3.3	4.0	V	
V _{CE(sat)}	Collector to Emitter Saturation Voltage		$I_{\rm C} = 20$ A, $V_{\rm GE} = 15$ V		-	1.19	-	V	
			I _C = 30A, V _G	I _C = 30A, V _{GE} = 15V		1.33	-	V	
			I _C = 50A, V _{GE} = 15V, T _C = 25°C		-	1.59	1.8	V	
			I _C = 50A, V _{GE} = 15V, T _C = 125 ^o C		-	1.66	-	V	
Dynamic C	haracterist	ics	- L						
C _{ies}	Input Capacitance			-	1295	-	pF		
C _{oes}	Output Ca		V _{CE} = 30V, V _{GE} = 0V, f = 1MHz		-	56	-	pF	
C _{res}	Reverse T	ransfer Capacitance			-	43	-	pF	
Switching	Characteris	tics			1	1			
t _{d(on)}	Turn-On D	elay Time			-	5	-	ns	
t _r	Rise Time		$V_{CC} = 200V,$	I _C = 20A,	-	20	-	ns	
t _{d(off)}	Turn-Off D	elay Time		$R_G = 5\Omega$, $V_{GE} = 15V$, ResistiveLoad, $T_C = 25^{\circ}C$		41	-	ns	
t _f	Fall Time				-	182	-	ns	
t _{d(on)}	Turn-On D	elay Time			-	4.6	-	ns	
t _r	Rise Time		$V_{CC} = 200V,$ Bo = 50, Vo		-	21	-	ns	
t _{d(off)}	Turn-Off D	elay Time	$R_G = 5\Omega$, V _{GE} = 15V, Resistive Load, T _C = 125 ^o C		-	43	-	ns	
t _f	Fall Time				-	249	-	ns	
Qg	Total Gate	Charge	$V_{} = 200V_{}$	L. – 20A	-	47	-	nC	
Q _{ge}	Gate to En	nitter Charge	V _{CE} = 200V _, V _{GE} = 15V	$1_{\rm C} = 20$ Å,	-	5.4	-	nC	
Q _{gc}	Gate to Co	llector Charge			-	15	-	nC	

Typical Performance Characteristics







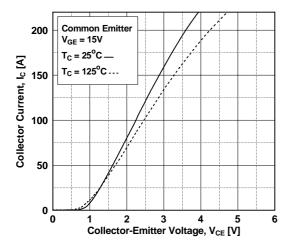


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

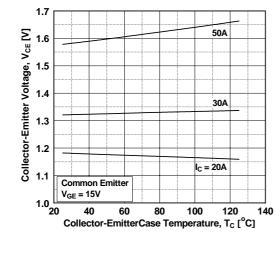


Figure 2. Typical Output Characteristics

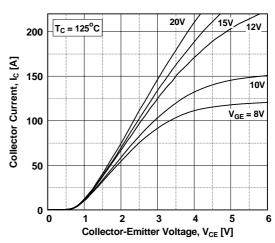


Figure 4. Transfer Characteristics

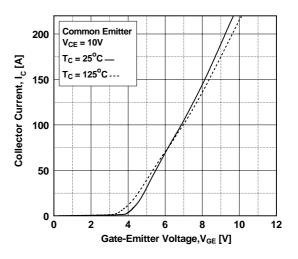
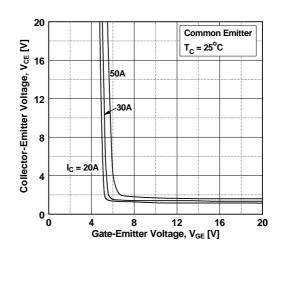


Figure 6. Saturation Voltage vs. V_{GE}



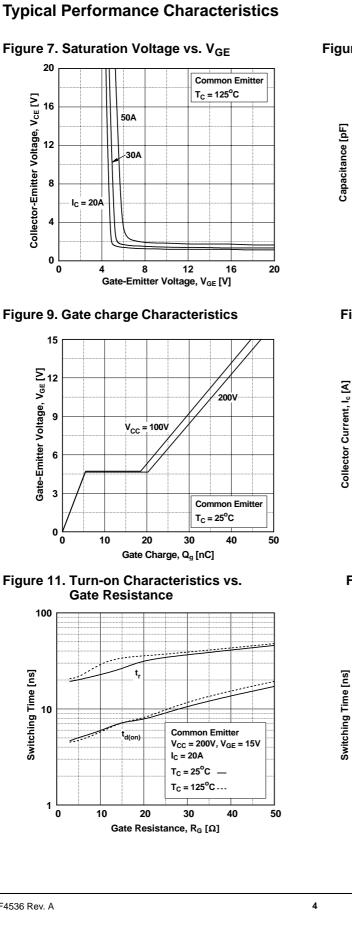


Figure 8. Capacitance Characteristics

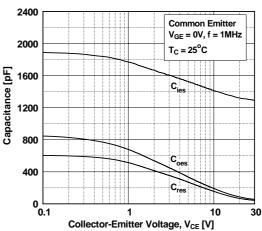


Figure 10. SOA Characteristics

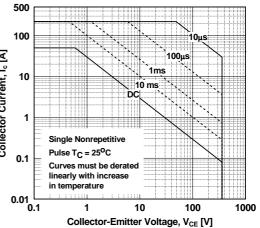
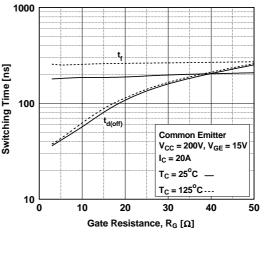
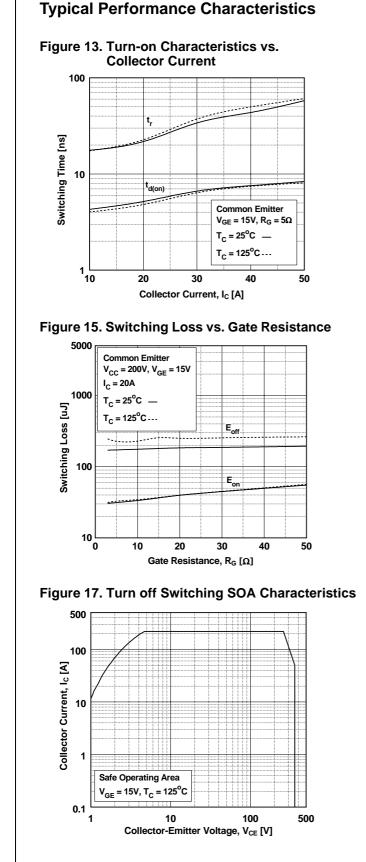
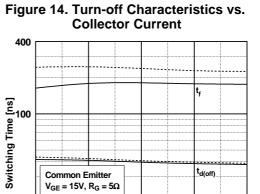


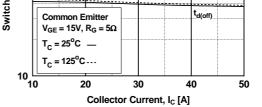
Figure 12. Turn-off Characteristics vs. **Gate Resistance**



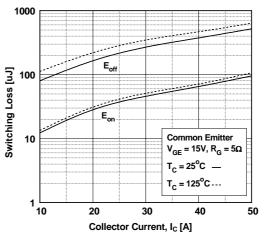
FGPF4536 360V, PDP Trench IGBT

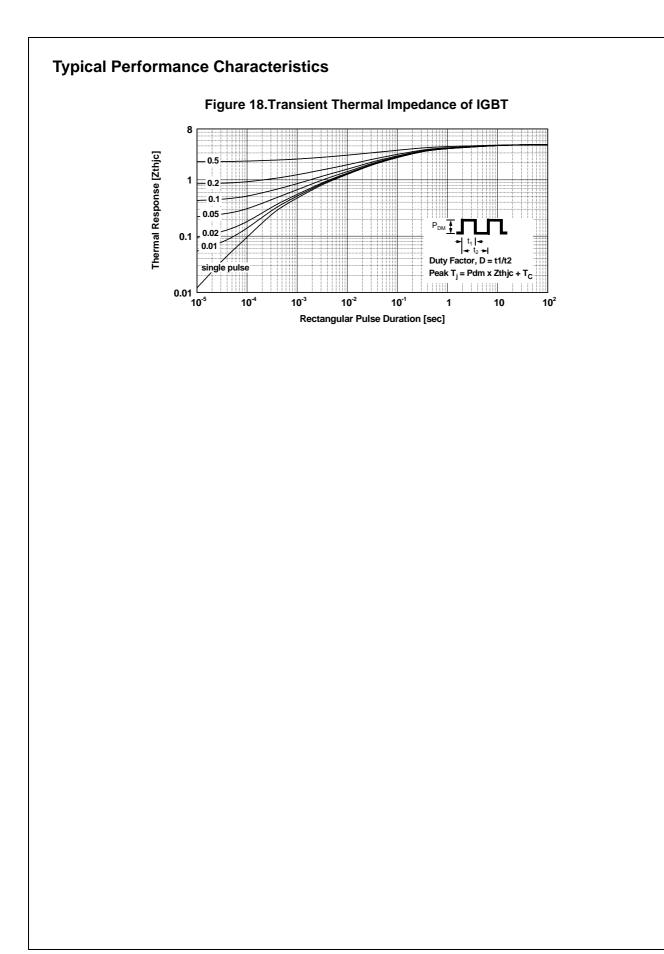


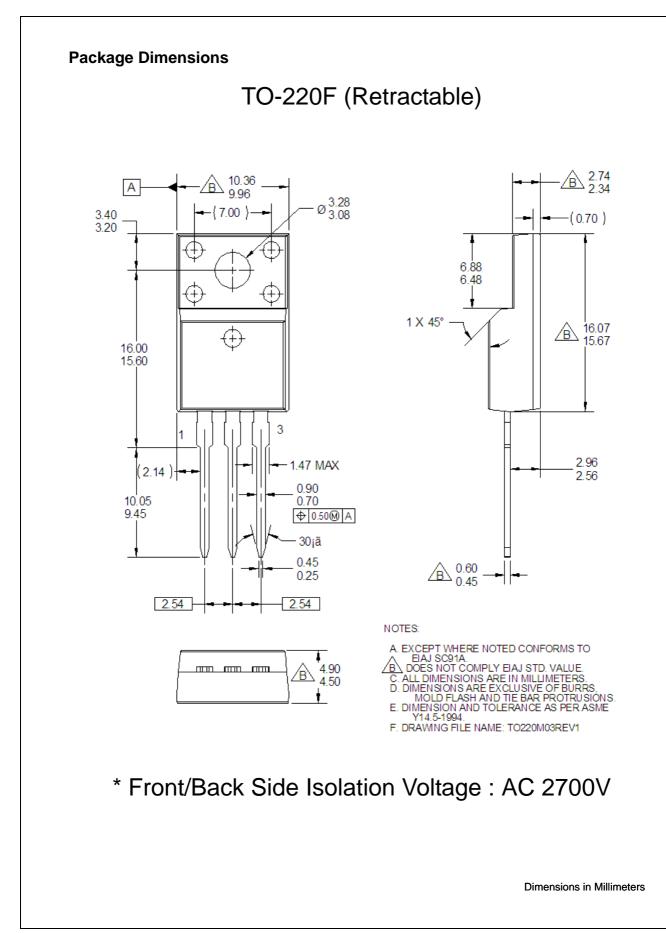














SEMICONDUCTOR

TRADEMARKS

AccuPower™

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

Power-SPM™

Auto-SPM™ Build it Now™ CorePLUS™ CorePOWER™ CROSSVOLT™ CTL™ Current Transfer Logic™ DFUXPEED Dual Cool™ EcoSPARK[®] EfficentMax™ ESBC™ F® Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT®

Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ Motion-SPM[™] OptiHiT™ **OPTOLOGIC**® **OPTOPLANAR[®]** PDP SPM™

F-PFS™

FRFFT®

Global Power ResourceSM

PowerTrench® PowerXS™ Programmable Active Droop™ QFĔT QS™ Quiet Series™ RapidConfigure™ ____тм Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ SPM® STEALTH™ SuperFET™ SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS™ SyncFET™ Sync-Lock™

The Power Franchise[®] the **D** wer TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic®

GENERAL

TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TriFault Detect™ TRUECURRENT™* µSerDes™



UniFET™ VCX™ VisualMax™ XS™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAST®

FPS™

FastvCore™

FETBench™

FlashWriter[®] *

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1 intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2 A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed Full Production		Datasheet contains final specifications. Fairchild Semiconductor reserves the rig make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		